

Features

1) Low on-resistance

4) Easy to parallel

5) Simple to drive

ApplicationSolar inverters

DC/DC converters

Induction heating

Motor drives

· Switch mode power supplies

2) Fast switching speed

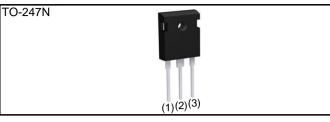
3) Fast reverse recovery

6) Pb-free lead plating ; RoHS compliant

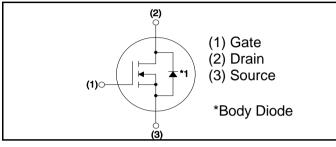
SCT3120AL N-channel SiC power MOSFET

V _{DSS}	650V
R _{DS(on)} (Typ.)	120mΩ
I_{D}^{*1}	21A
P _D	103W

Outline



Inner circuit



Packaging specifications

	Packing	Tube
	Reel size (mm)	-
Turno	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	30
	Taping code	C11
	Marking	SCT3120AL

●Absolute maximum ratings (T_{vj} = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit	
Drain - Source Voltage		V _{DSS}	650	V	
Continuous Drain surrant	$T_c = 25^{\circ}C$	I _D ^{*1}	21	А	
Continuous Drain current	$T_c = 100^{\circ}C$	I _D ^{*1}	15	А	
Pulsed Drain current ($T_c = 25^{\circ}C$)		I _{D,pulse} ^{*2}	52	А	
Gate - Source voltage (DC)		V _{GSS}	-4 to +22	V	
Gate - Source surge voltage (t _{surge} < 300nsec)		V _{GSS_surge} *3	-4 to +26	V	
Recommended drive voltage		V _{GS_op} ^{*4}	0 / +18	V	
Virtual Junction temperature		T _{vj}	175	°C	
Range of storage temperature		T _{stg}	-55 to +175	°C	

•Electrical characteristics ($T_{vj} = 25^{\circ}C$ unless otherwise specified)

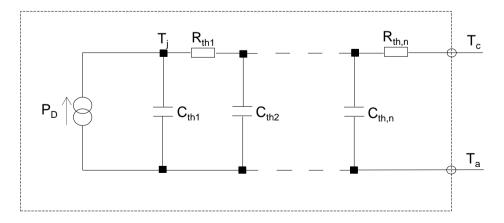
Doromotor	Symbol	Conditions	Values			Unit	
Parameter	Symbol Conditions –		Min.	Тур.	Max.	Offic	
		$V_{GS} = 0V, I_D = 1mA$					
Drain - Source breakdown voltage	$V_{(BR)DSS}$	$T_{vj} = 25^{\circ}C$	650	-	-	V	
go		T _{vj} = -55°C	650	-	-		
		$V_{GS} = 0V, V_{DS} = 650V$					
Zero Gate voltage Drain current	I_{DSS}	$T_{vj} = 25^{\circ}C$	-	1	10	μA	
		T _{vj} = 150°C	-	2	-		
Gate - Source leakage current	I _{GSS+}	$V_{GS} = +22V$, $V_{DS} = 0V$	-	-	100	nA	
Gate - Source leakage current	I _{GSS-}	$V_{GS} = -4V$, $V_{DS} = 0V$	-	-	-100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = 10V, I_{D} = 3.33mA$	2.7	-	5.6	V	
		$V_{GS} = 18V, I_{D} = 6.7A$					
Static Drain - Source on - state resistance	${\sf R}_{\sf DS(on)}$ *5	T _{vj} = 25°C	-	120	156	mΩ	
		T _{vj} = 150°C	-	172	-		
Gate input resistance	R_G	f = 1MHz, open drain	-	18	-	Ω	

Thermal resistance

Parameter	Symbol	Values			Unit
Falanletei	Symbol		Тур.	Max.	Offic
Thermal resistance, junction - case	R _{thJC}	-	1.12	1.46	K/W

•Typical Transient Thermal Characteristics

Symbol	Value	Unit	Symbol	Value	Unit
R _{th1}	1.11E-01		C _{th1}	8.73E-04	
R _{th2}	7.09E-01	K/W	C _{th2}	5.10E-03	Ws/K
R _{th3}	3.01E-01		C _{th3}	2.94E-02	





•Electrical characteristics (T_{vj} = 25°C unless otherwise specified)

Dorometer	Symbol	nbol Conditions		Values		Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Transconductance	g _{fs} *5	$V_{DS} = 10V, I_{D} = 6.7A$	-	2.7	-	S
Input capacitance	C _{iss}	$V_{GS} = 0V$	-	460	-	
Output capacitance	C _{oss}	V _{DS} = 500V	-	35	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	16	-	
Effective output capacitance, energy related	C _{o(er)}	$V_{GS} = 0V$ $V_{DS} = 0V$ to 300V	-	70	-	pF
Total Gate charge	Q_g^{*5}	$V_{DS} = 300V$ $I_{D} = 6.7A$	-	38	-	
Gate - Source charge	Q_{gs}^{*5}	$V_{GS} = 18V$	-	10	-	nC
Gate - Drain charge	Q_{gd} *5	See Fig. 1-1.	-	18	-	
Turn - on delay time	t _{d(on)} *5	$V_{DS} = 300V$ $I_{D} = 6.7A$	-	14	-	
Rise time	t _r *5	V _{GS} = 0V/+18V	-	21	-	ns
Turn - off delay time	t _{d(off)} *5	$R_{G} = 0\Omega$ $R_{L} = 45\Omega$	-	23	-	115
Fall time	t _f *5	See Fig. 1-1, 1-2.	-	14	-	
Turn - on switching loss	E _{on} *5	$V_{DS} = 300V$ $V_{GS}=0V/18V, I_{D} = 6.7A$ $R_{G} = 0\Omega, L = 500\mu H$	-	29	-	
Turn - off switching loss	E _{off} *5	E_{on} includes diode reverse recovery L_{σ} = 50nH, C _{σ} = 200pF See Fig. 2-1, 2-2.	-	3	-	Lμ



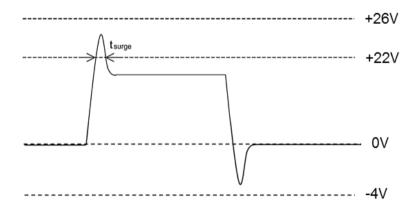
●Body diode electrical characteristics (Source-Drain) (T_{vj} = 25°C unless otherwise specified)

Parameter	Symbol	Conditions		Values		Unit
Faidifielei	Symbol	Conditions	Min.	Тур.	Max.	Offic
Body diode continuous, forward current	ا _S *1	T _c = 25°C	-	-	21	А
Body diode direct current, pulsed	I_{SM} *2	T _c = 25 0	-	-	52	А
Forward voltage	V_{SD} *5	$V_{GS} = 0V, I_{S} = 6.7A$	-	3.2	-	V
Reverse recovery time	t _{rr} *5	$I_F = 6.7A$ $V_R = 300V$	-	13	-	ns
Reverse recovery charge	Q _{rr} *5	v _R = 3000 di/dt = 1100A/μs	-	35	-	nC
Peak reverse recovery current	l _{rrm} *5	$L_{\sigma} = 50$ nH, $C_{\sigma} = 200$ pF See Fig. 3-1, 3-2.	-	6	-	А

*1 Limited by maximum T_{vj} and for Max. R_{thJC} .

*2 PW \leq 10µs, Duty cycle \leq 1%

*3 Example of acceptable V_{GS} waveform



- *4 Please be advised not to use SiC-MOSFETs with V_{GS} below 13V as doing so may cause thermal runaway.
- *5 Pulsed



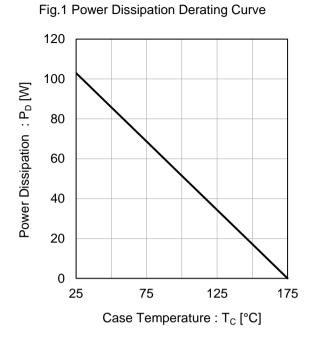
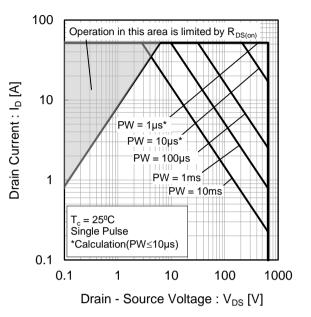
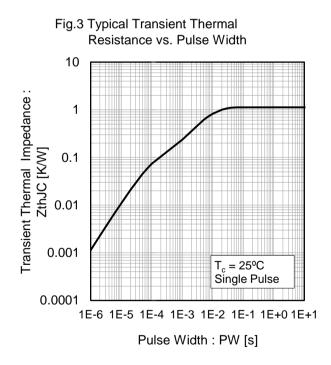


Fig.2 Maximum Safe Operating Area







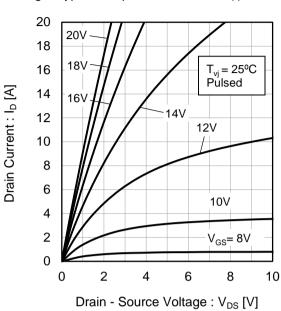


Fig.4 Typical Output Characteristics(I)

Fig.5 Typical Output Characteristics(II)

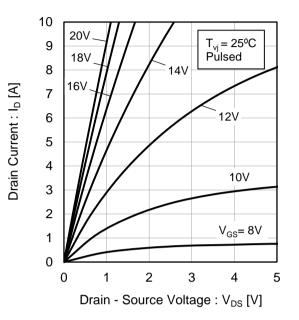
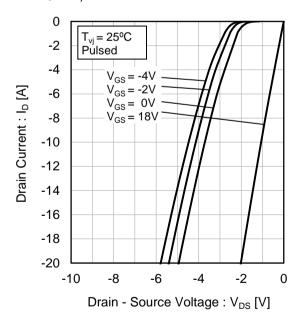


Fig.6 T_{vi} = 25°C 3rd Quadrant Characteristics







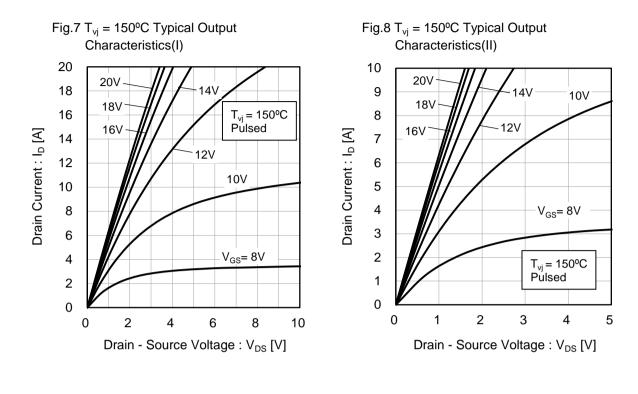


Fig.9 T_{vj} = 150°C 3rd Quadrant Characteristics

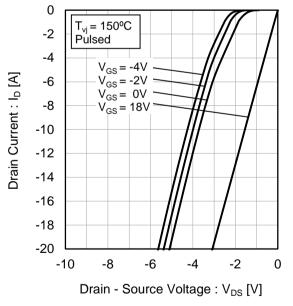
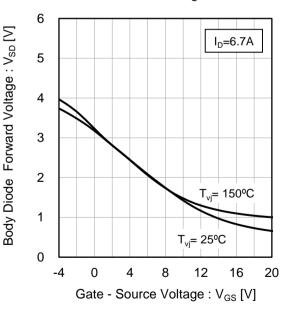


Fig.10 Body Diode Forward Voltage vs. Gate - Source Voltage



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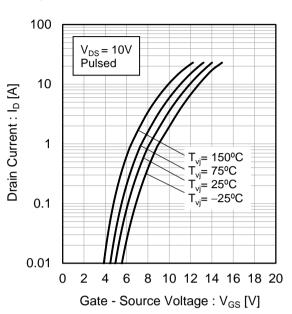
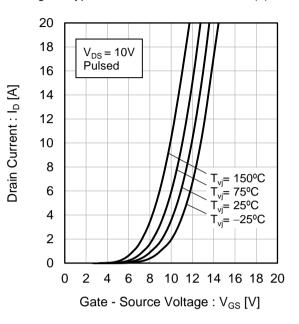


Fig.11 Typical Transfer Characteristics (I)

Fig.12 Typical Transfer Characteristics (II)



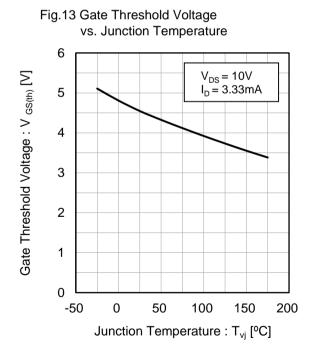
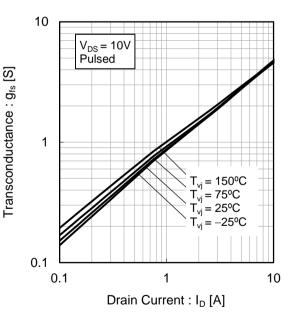
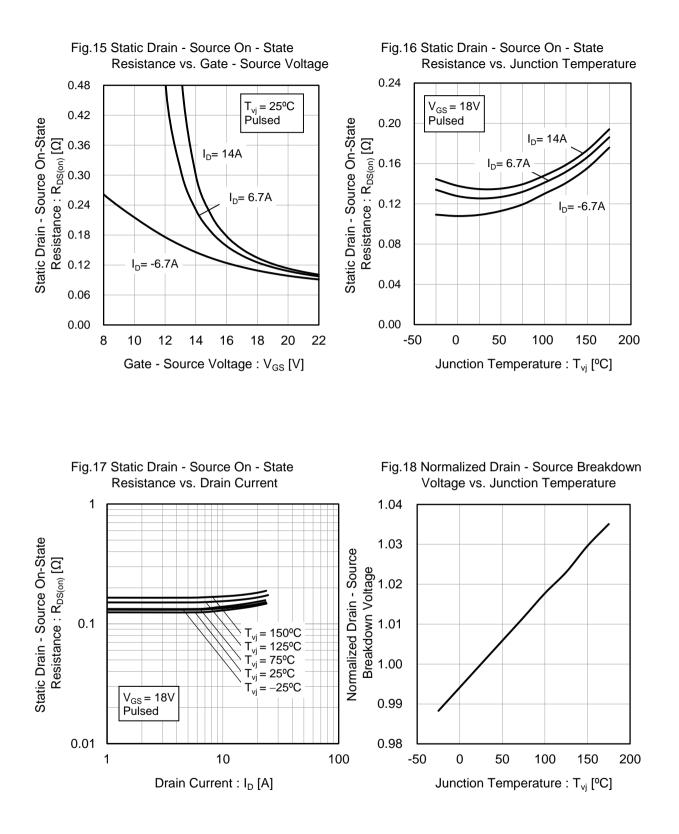


Fig.14 Transconductance vs. Drain Current











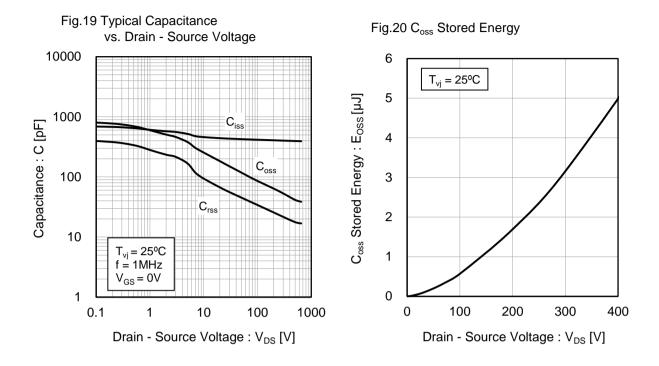
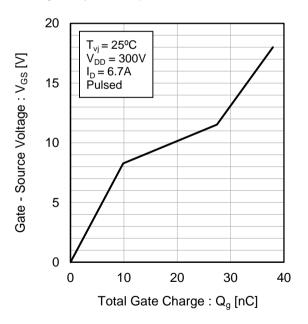
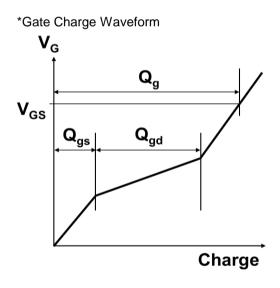
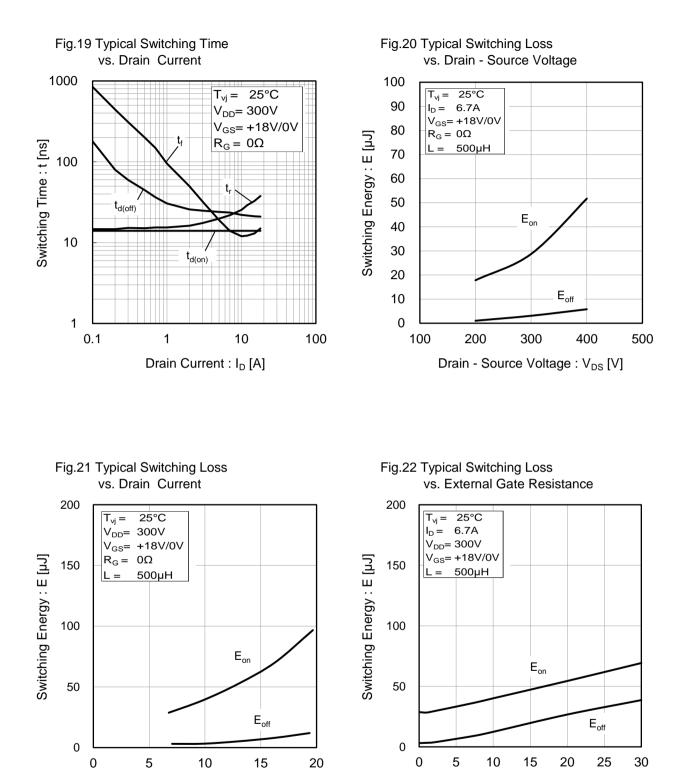


Fig.21 Dynamic Input Characteristics









Drain Current : I_D [A]



External Gate Resistance : $R_G [\Omega]$

Measurement circuits and waveforms

Fig.1-1 Gate Charge and Switching Time Measurement Circuit

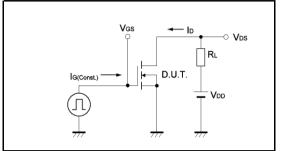


Fig.2-1 Switching Energy Measurement Circuit

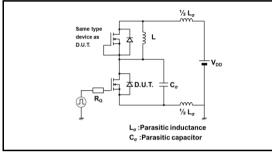


Fig.3-1 Reverse Recovery Time Measurement Circuit

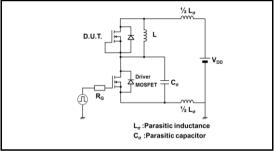


Fig.1-2 Waveforms for Switching Time

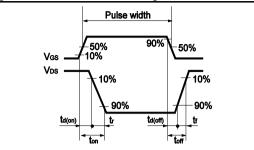


Fig.2-2 Waveforms for Switching Energy Loss

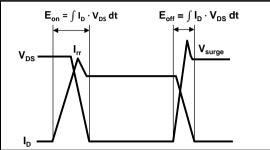
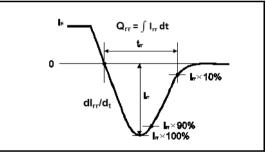
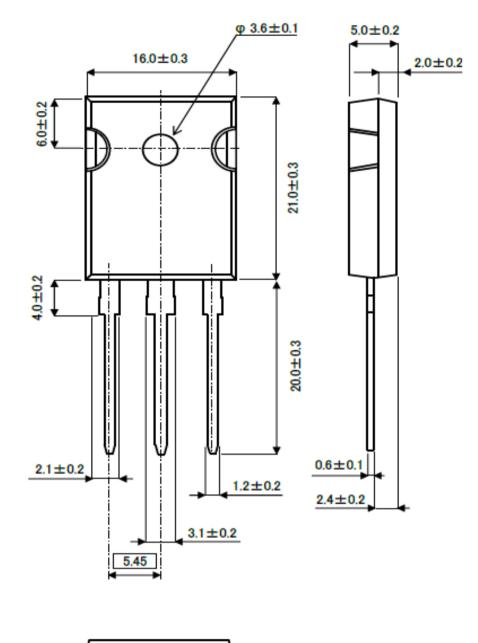


Fig.3-2 Reverse Recovery Waveform





Package Dimensions

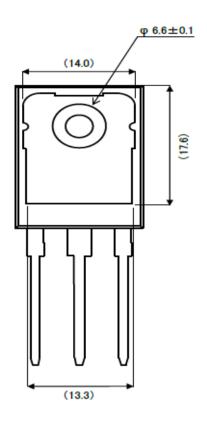




Unit: mm





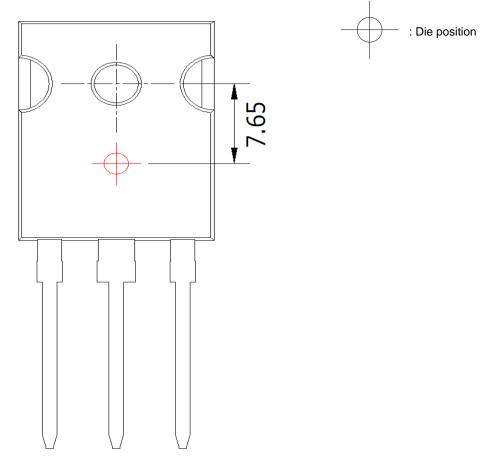


Unit: mm





Die Bonding Layout



•Front view of the packaging.

•Dimensions are design values.

·If the heat sink is to be installed, it should be in contact with the die bonding point.

Unit: mm





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